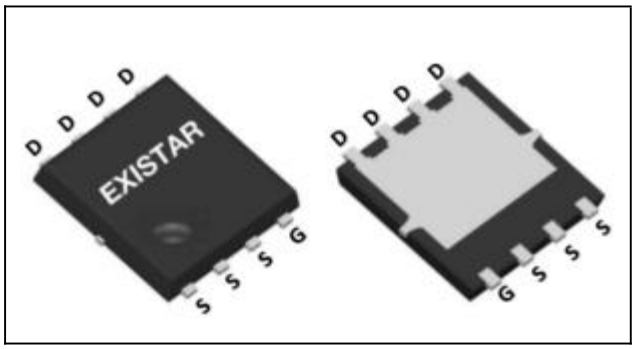
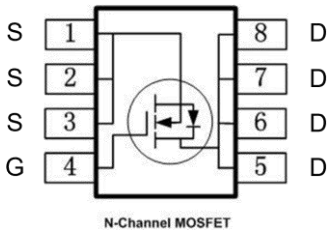
N-Channel 100V MOSFET

E100N016HL1

V_{DS} (V)	$R_{DS(on),max}$ (mΩ)	I_D (A)
100V	16 @ V_{GS} = 10V	55

PDFN5X6





Pb-free
RoHS COMPLIANT
HALOGEN FREE

Features

- Low $R_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed
- 100% avalanche tested

Applications

- DC/DC conversion
- Power switch
- PD charger
- Moto driver

Package And Ordering Information

Ordering code	Package	Marking
E100N016HL1	PDFN5x6	E100N016HL1

Ordering Information

Package	Units/ Reel	Reels/ Inner Box	Units/ Inner Box
PDFN5x6	5000	1	5000

Key Performance Parameters

Parameter	Value	Unit
VDS, min @ Tj(max)	100	V
ID, pulse	220	A
RDS(ON), max @ VGS=10V	16	mΩ
Qg	25.6	nC

Absolute Maximum Ratings at Tj=25°C Unless Otherwise Noted

Parameter		Symbol	Limit	Unit
Drain-source voltage		V_{DS}	100	V
Gate-source voltage		V_{GS}	±20	
Continuous drain current	T_C=25°C	I_D	55	A
	T_C=100°C		35	
Pulsed drain current		$I_{D,pulse}$	220	
Avalanche energy, single pulse		E_{AS}	30	mJ
Power dissipation	T_C=25°C	P_D	100	W
	T_A=25°C		-	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to 150	℃

Thermal Characteristics

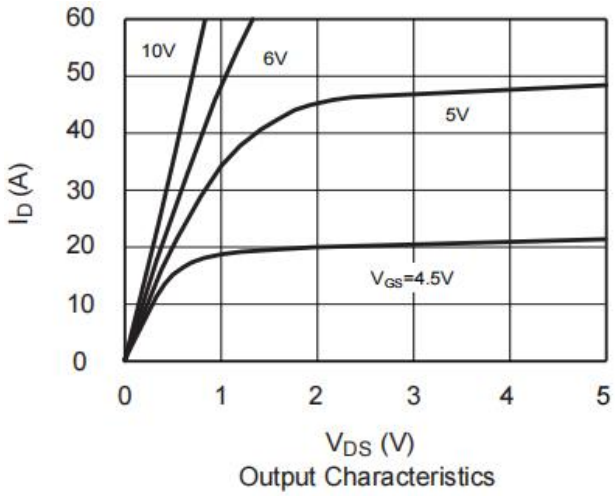
Parameter		Symbol	Max.	Unit
Thermal resistance, junction-to-case	Steady state	$R_{\theta JC}$	1.25	°C/W
Thermal resistance, junction-to-ambient	Steady state	$R_{\theta JA}$	52	

Electrical Characteristics at Tj=25°C unless otherwise specified

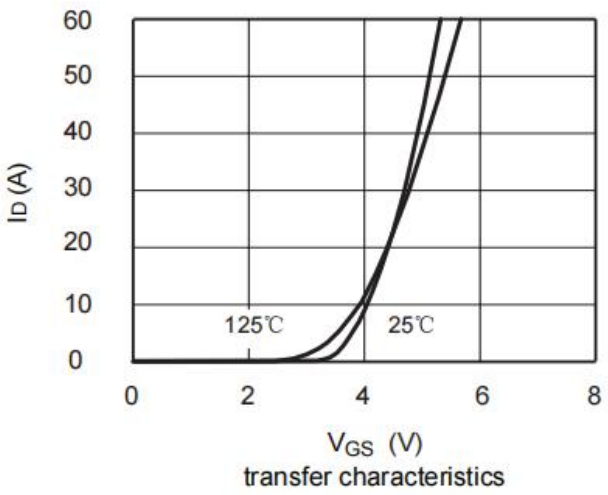
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Static						
Drain to source breakdown voltage	$V_{(BR)DSS}$	100			V	V_{GS} = 0, I_D = 250 μA
Gate-source threshold voltage	$V_{GS(th)}$	1	1.6	2.3	V	V_{DS} = V_{GS}, I_D = 250 μA
Gate-body leakage	I_{GSS}			±100	nA	V_{DS} = 0 V, V_{GS} = ±20 V
Zero gate voltage drain current	I_{DSS}			1	μA	V_{DS} = 100 V, V_{GS} = 0 V
Drain-source on-resistance	$R_{DS(on)}$		13.8	16	mΩ	V_{GS} = 10 V, I_D = 20 A
Drain-source on-resistance	$R_{DS(on)}$		17.8	20	mΩ	V_{GS} = 4.5 V, I_D = 15 A
Gate resistance	Rg		1.5		Ω	f=1MHz

Gate Charge						
Total gate charge	Qg		25.6		nC	V_{DS} = 50 V, I_D = 25 A, V_{GS} = 10 V
Gate-source charge	Qgs		10			
Gate-drain charge	Qgd		7.5			
Dynamic						
Turn-on delay time	$t_{d(on)}$		13		ns	V_{DS} = 50 V, V_{GS} = 10 V, R_{G_ext}= 2.7 Ω
Rise time	t_r		41			
Turn-off delay time	$t_{d(off)}$		22			
Fall time	t_f		11			
Input capacitance	C_{iss}		1075		pF	V_{DS} =25 V, V_{GS} = 0 V, f = 1MHz
Output capacitance	C_{oss}		503			
Reverse transfer capacitance	C_{rss}		40			
Body Diode						
Diode forward voltage	V_{SD}		0.85	1.2	V	V_{GS} = 0 V, I_F = 20 A

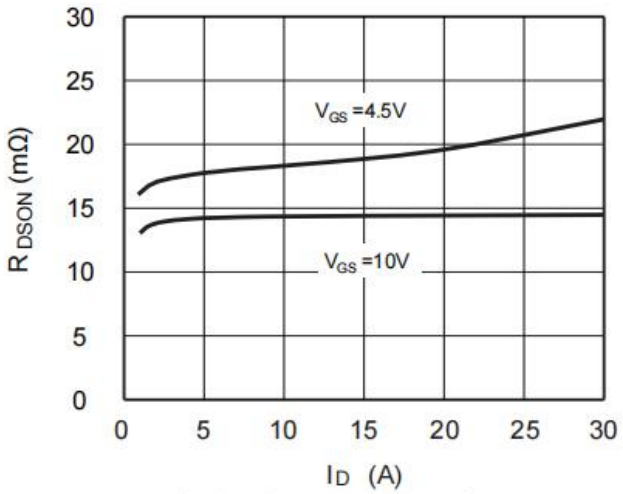
Electrical Characteristics Diagrams



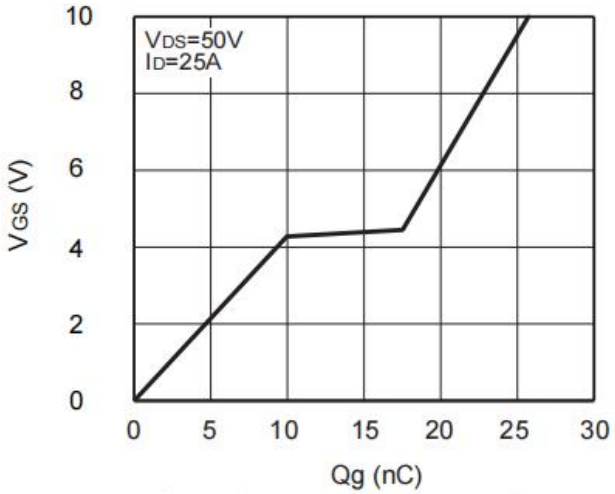
Output Characteristics



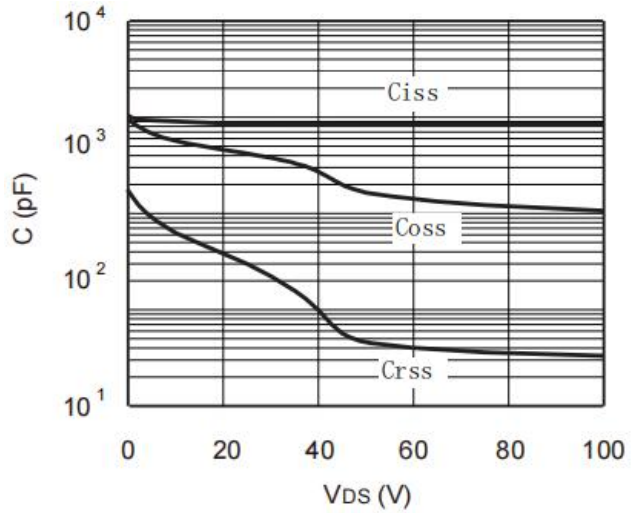
transfer characteristics



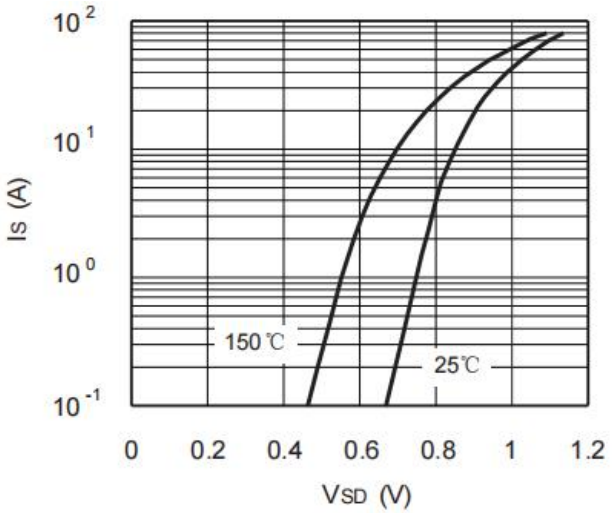
On-Resistance vs. Drain Current



Gate charge vs gate-source voltage

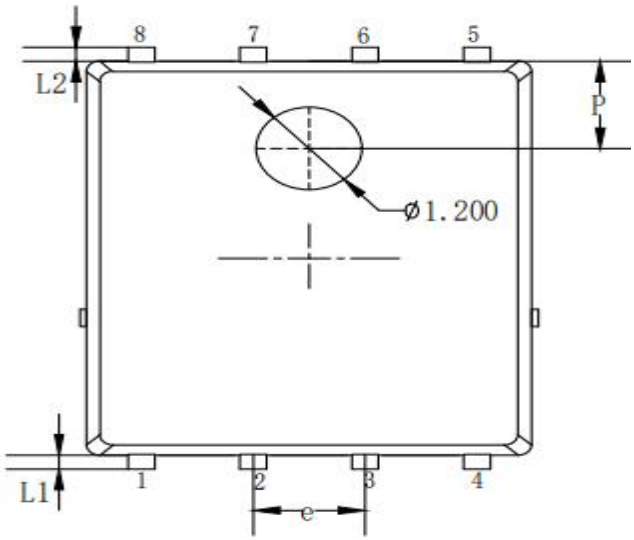


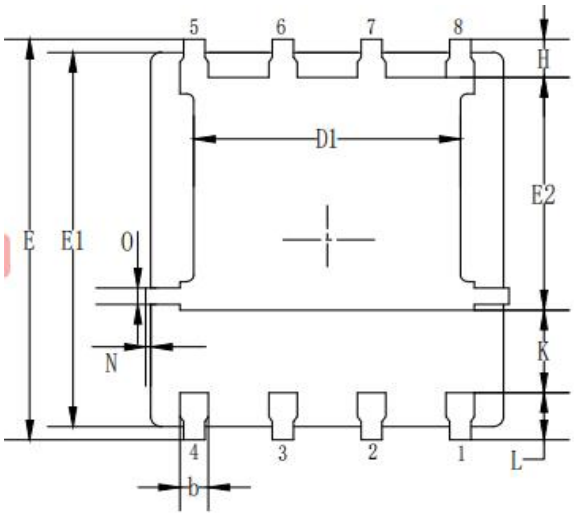
Capacitance Characteristics

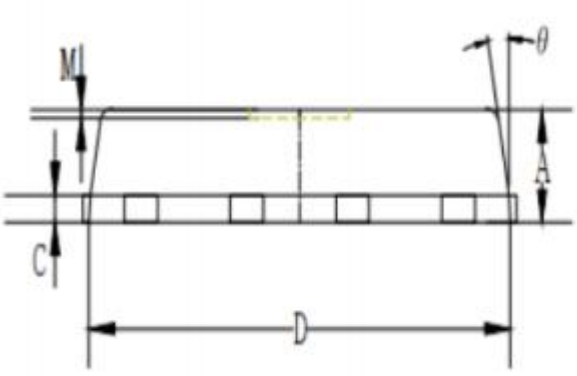


Body-Diode Characteristics

Package Outline Dimensions







Symbols	Millimeters		
	MIN.	NOM.	MAX.
A	0.90	1.05	1.20
b	0.35	0.40	0.50
C	0.20	0.25	0.35
D	4.90	5.05	5.10
D1	3.72	3.82	3.92
E	6.00	6.15	6.25
E1	5.60	5.75	5.90
E2	3.47	3.57	3.67
e	1.27 BSC.		
H	0.48	0.58	0.68
K	1.17	1.27	1.37
L	0.64	0.69	0.75
L1/L2	0.10 ~ 0.20		
θ	8°	10°	12°
M	0.08 REF.		
N	0	–	0.15
O	0.25 REF.		
P	1.28 REF.		

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